

RJH60D5BDPQ-E0#T2

RJH60D5BDPQ-E0#T2 Information



For Reference Only

Part Number RJH60D5BDPQ-E0#T2

Manufacturer Renesas Electronics America

Category Discrete Semiconductor Products
Transistors - IGBTs - Single

 $\textbf{Description} \qquad \text{IGBT 600V 75A 200W TO-247}$

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RJH60D5BDPQ-E0#T2 Specifications

Manufacturer Part Number	RJH60D5BDPQ-E0#T2
Manufacturer	Renesas Electronics America
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3
Series	-
IGBT Type	Trench
Voltage - Collector Emitter Breakdown (Max)	600V
Current - Collector (Ic) (Max)	75A
Current - Collector Pulsed (Icm)	-
Vce(on) (Max) @ Vge, Ic	2.2V @ 15V, 37A
Power - Max	200W
Switching Energy	400μJ (on), 810μJ (off)
Input Type	Standard
Gate Charge	78nC
Td (on/off) @ 25°C	50ns/130ns
Test Condition	300V, 37A, 5 Ohm, 15V
Reverse Recovery Time (trr)	25ns
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	TO-247
	Report errors?

RJH60D5BDPQ-E0#T2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RJH60D5BDPQ-E0#T2 Payment Methods



















RJH60D5BDPQ-E0#T2 Shipping Methods













If you have any question about RJH60D5BDPQ-E0#T2, please do not hesitate to contact us!

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